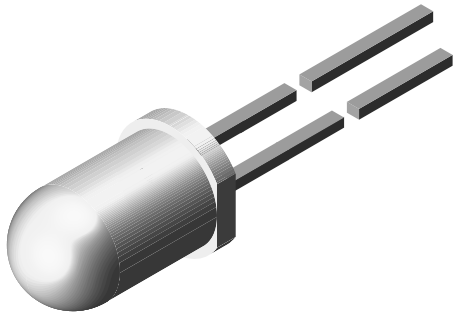
High Speed Infrared Emitting Diode, 830 nm, GaAlAs Double Hetero



FEATURES

- Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): ∅ 5
- Peak wavelength: λ_p = 830 nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: φ = ± 10°
- Low forward voltage
- Suitable for high pulse current operation
- High modulation bandwidth: f_c = 18 MHz
- Good spectral matching with CMOS cameras
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE
GREEN (5-2008)

DESCRIPTION

TSHG8200 is an infrared, 830 nm emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in a clear, untinted plastic package.

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras (illumination)
- High speed IR data transmission
- Smoke-automatic fire detectors

PRODUCT SUMMARY				
COMPONENT	I_e (mW/sr)	φ (°)	λ_p (nm)	t_r (ns)
TSHG8200	180	± 10	830	20

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TSHG8200	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 µs	I_{FM}	200	mA
Surge forward current	t_p = 100 µs	I_{FSM}	1	A
Power dissipation		P_V	180	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	-40 to +85	°C
Storage temperature range		T_{stg}	-40 to +100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction to ambient	J-STD-051, leads 7 mm soldered on PCB	R_{thJA}	230	K/W

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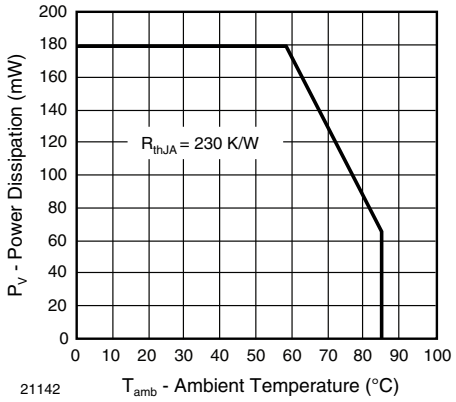

Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

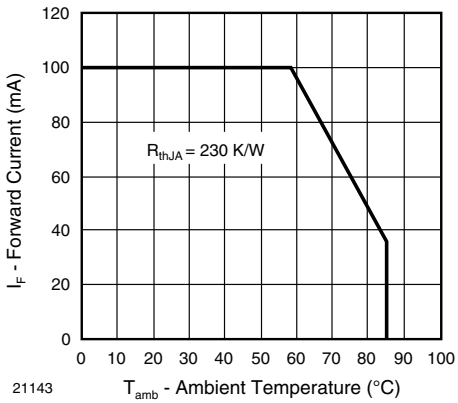

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F	-	1.5	1.8	V
	I_F = 1 A, t_p = 100 µs	V_F	-	2.3	-	V
Temperature coefficient of V_F	I_F = 1 mA	TK_{VF}	-	-1.8	-	mV/K
Reverse current	V_R = 5 V	I_R	-	-	10	µA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_j	-	125	-	pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	120	180	360	mW/sr
	I_F = 1 A, t_p = 100 µs	I_e	-	1600	-	mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕ_e	-	50	-	mW
Temperature coefficient of ϕ_e	I_F = 100 mA	$TK\phi_e$	-	-0.35	-	%/K
Angle of half intensity		φ	-	± 10	-	°
Peak wavelength	I_F = 100 mA	λ_p	-	830	-	nm
Spectral bandwidth	I_F = 100 mA	$\Delta\lambda$	-	40	-	nm
Temperature coefficient of λ_p	I_F = 100 mA	$TK\lambda_p$	-	0.25	-	nm/K
Rise time	I_F = 100 mA	t_r	-	20	-	ns
Fall time	I_F = 100 mA	t_f	-	13	-	ns
Cut-off frequency	I_{DC} = 70 mA, I_{AC} = 30 mA pp	f_c	-	18	-	MHz
Virtual source diameter		d	-	3.7	-	mm

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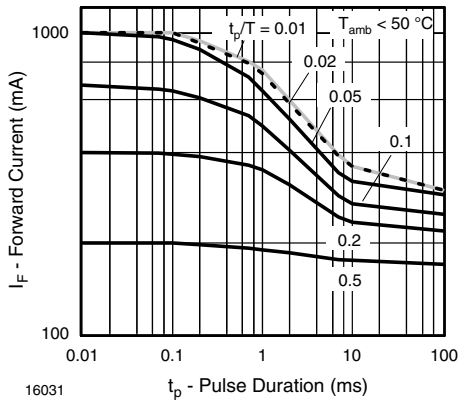

Fig. 3 - Pulse Forward Current vs. Pulse Duration

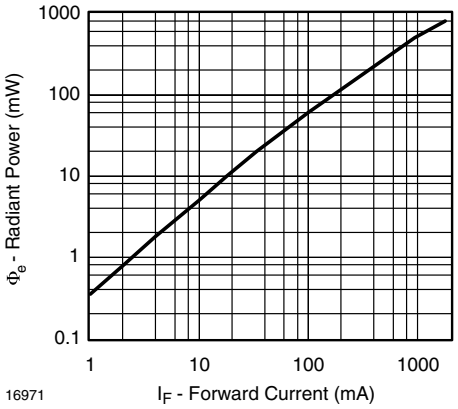

Fig. 6 - Radiant Power vs. Forward Current

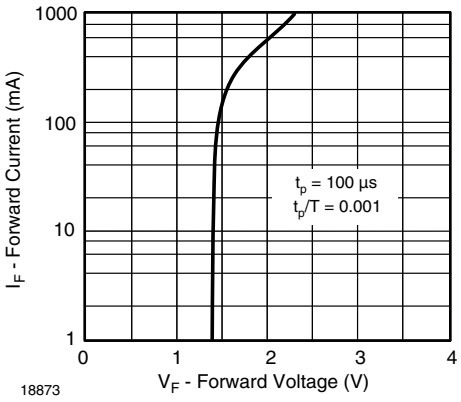

Fig. 4 - Forward Current vs. Forward Voltage

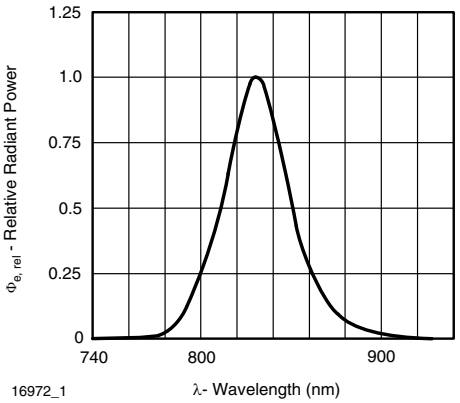

Fig. 7 - Relative Radiant Power vs. Wavelength

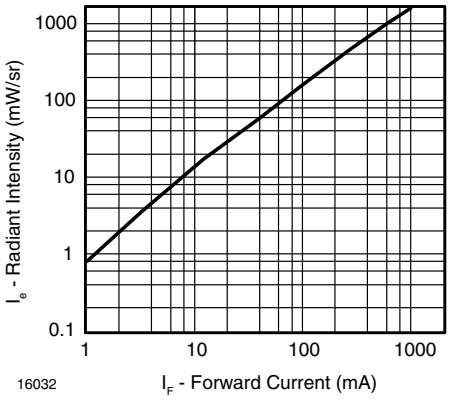

Fig. 5 - Radiant Intensity vs. Forward Current

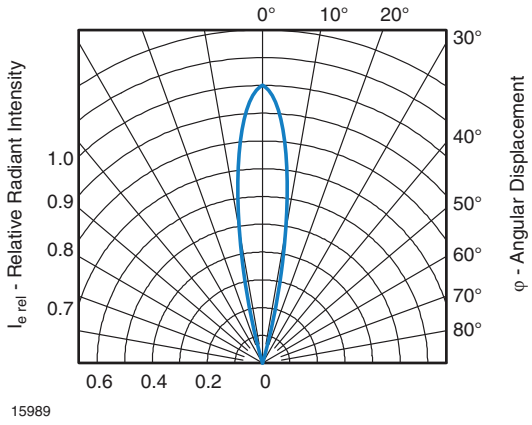

Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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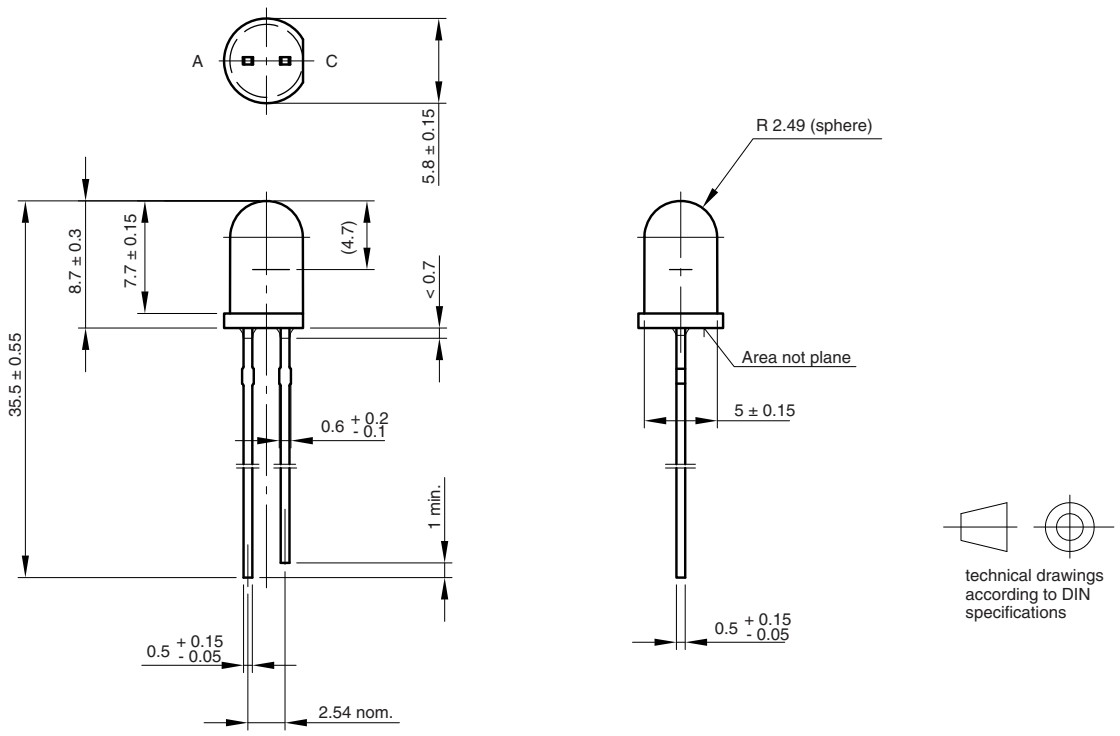
PACKAGE DIMENSIONS in millimeters



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